TOSHIBA Field Effect Transistor Silicon N Channel MOS Type (π–MOSIII)

2SK2968

DC-DC Converter, Relay Drive and Motor Drive Applications

• Low drain–source ON resistance : RDS (ON) = 1.05 Ω (typ.)

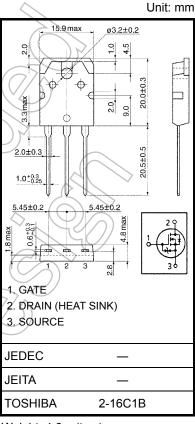
• High forward transfer admittance $: |Y_{fs}| = 7.6 \text{ S (typ.)}$

• Low leakage current $: I_{DSS} = 100 \mu A \text{ (max) (V}_{DS} = 720 \text{ V)}$

• Enhancement mode : $V_{th} = 2.0 \text{ to } 4.0 \text{ V (V}_{DS} = 10 \text{ V, I}_{D} = 1 \text{ mA})$

Absolute Maximum Ratings (Ta = 25°C)

Characteris	stics	Symbol	Rating	(Unit)
Drain-source voltage		V_{DSS}	900	V
Drain-gate voltage (Ro	$_{\rm SS}$ = 20 k Ω)	V_{DGR}	900	V
Gate-source voltage		V_{GSS}	±30	> ∨
Drain current	DC (Note 1)	ΙD	(10)	Α
	Pulse (Note 1)	I _{DP}	30	A
Drain power dissipation	n (Tc = 25°C)	PD	150	/_w
Single pulse avalanche	e energy (Note 2)	EAS	810	mJ
Avalanche current		IAR	10	A
Repetitive avalanche e	nergy (Note 3)	(E _{AR}))	15	μŊ
Channel temperature	(Tch	150	°C
Storage temperature ra	ange	T _{stg}	-55 to 150	°C



Weight: 4.6 g (typ.)

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Thermal Characteristics

Characteristics	Symbol	Max	Unit
Thermal resistance, channel to case	Rth (ch-c)	0.833	°C/W
Thermal resistance, channel to ambient	R _{th (ch-a)}	50	°C / W

Note 1: Ensure that the channel temperature does not exceed 150°C.

Note 2: V_{DD} = 90 V, T_{ch} = 25°C (initial), L = 14.9 mH, R_G = 25 Ω , I_{AR} = 10 A

Note 3: Repetitive rating: pulse width limited by maximum channel temperature

This transistor is an electrostatic-sensitive device.

Please handle with caution.

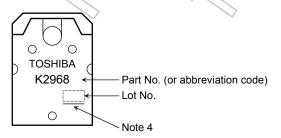
Electrical Characteristics (Ta = 25°C)

Charac	cteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage cu	irrent	I _{GSS}	V _{GS} = ±30 V, V _{DS} = 0 V	_	_	±10	μΑ
Gate-source bre	eakdown voltage	V (BR) GSS	I _G = ±10 μA, V _{DS} = 0 V	±30	_	_	V
Drain cut-off cu	rrent	I _{DSS}	V _{DS} = 720 V, V _{GS} = 0 V	/	_	100	μΑ
Drain-source br	eakdown voltage	V _{(BR) DSS}	I _D = 10 mA, V _{GS} = 0 V	900		1	V
Gate threshold v	oltage/	V_{th}	V _{DS} = 10 V, I _D = 1 mA	2.0) /_	4.0	V
Drain-source O	N resistance	R _{DS} (ON)	V _{GS} = 10 V, I _D = 4 A)_ 	1.05	1.25	Ω
Forward transfer	r admittance	Y _{fs}	V _{DS} = 15 V, I _D = 4 A	3.5	7.6	_	S
Input capacitano	e	C _{iss}		_	2150	_	
Reverse transfe	r capacitance	C _{rss}	V _{DS} = 25 V, V _{GS} = 0 V, f = 1 MHz	_	35	_	pF
Output capacitance		Coss		_	220	_	
Switching time	Rise time	t _r	VCS ID=5A	- (25	⟩ I _{>}	
	Turn-on time	t _{on}	$V_{\rm GS}$ $_{0\rm V}$ $R_{\rm L}$ $= 80\Omega$	1	60) –	ns
	Fall time	t _f	V _{DD} ≒400V	7	25	_	115
	Turn-off time	t _{off}	Duty ≤1%, t _w =10μs) –	120	_	
Total gate charg plus gate-drain)		Qg		ı	70	ı	
Gate-source charge Q _{gs}		Q _{gs}	$V_{DD} \approx 400 \text{ V}, V_{GS} = 10 \text{ V}, I_{D} = 10 \text{ A}$	_	37	_	nC
Gate-drain ("miller") Charge Qgd		Q _{gd}		_	33	_	

Source-Drain Ratings and Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Continuous drain reverse current (Note 1)	I _{DR}	_	_	_	10	Α
Pulse drain reverse current (Note 1)	I _{DRP}	_	_	_	30	Α
Forward voltage (diode)	V _{DSF}	I _{DR} = 10 A, V _{GS} = 0 V	_	_	-1.9	V
Reverse recovery time	t _{rr}	I _{DR} = 10 A, V _{GS} = 0 V dI _{DR} / dt = 100 A / μs	_	1300	_	ns
Reverse recovery charge	Qrr		_	14.5	_	μC

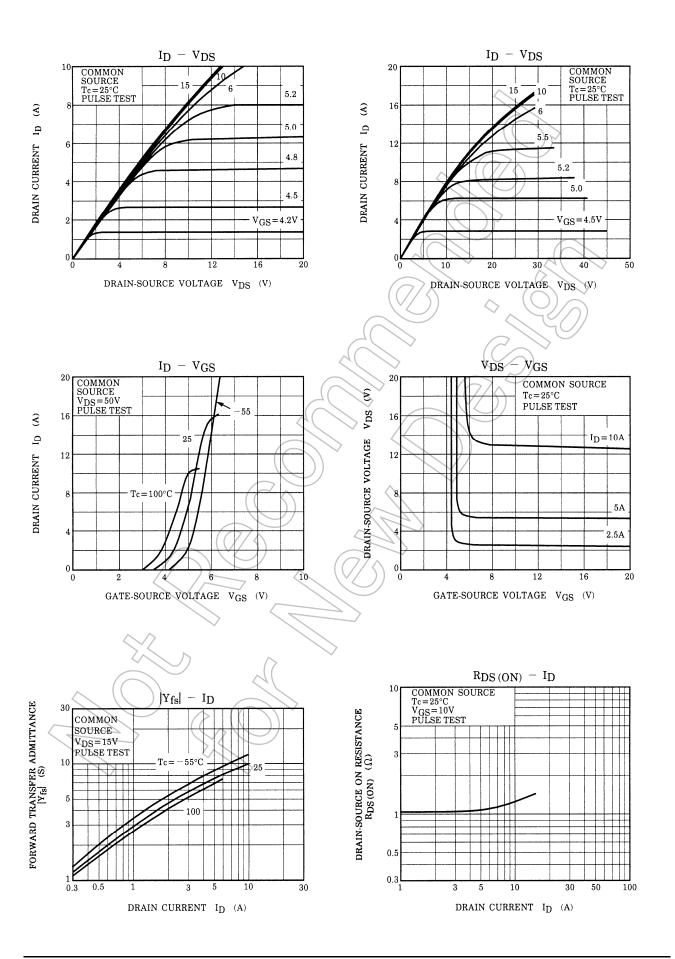
Marking

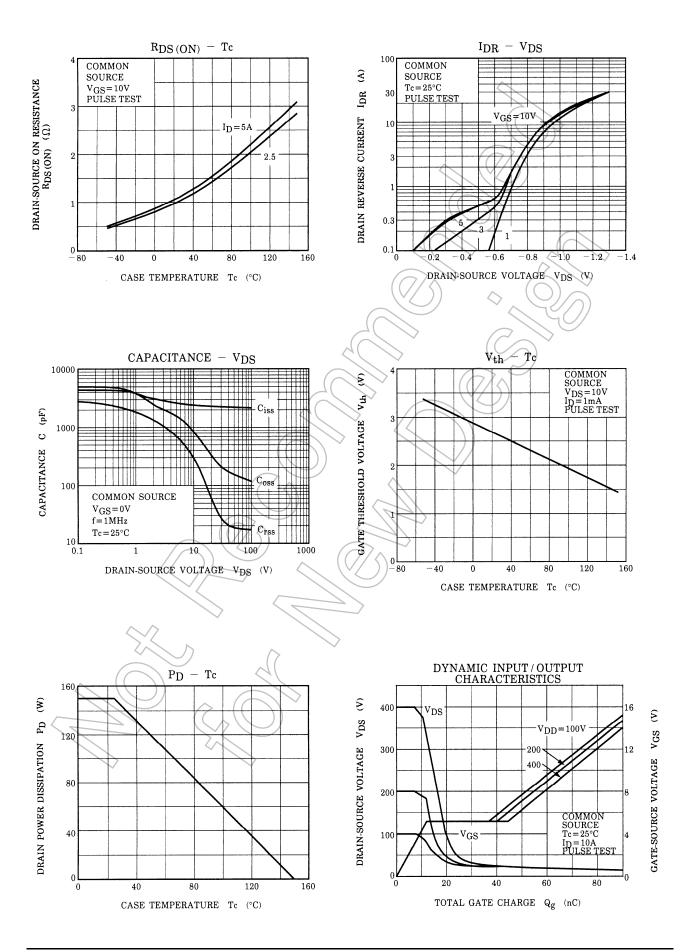


Note 4: A line under a Lot No. identifies the indication of product Labels.

Not underlined: [[Pb]]/INCLUDES > MCV Underlined: [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

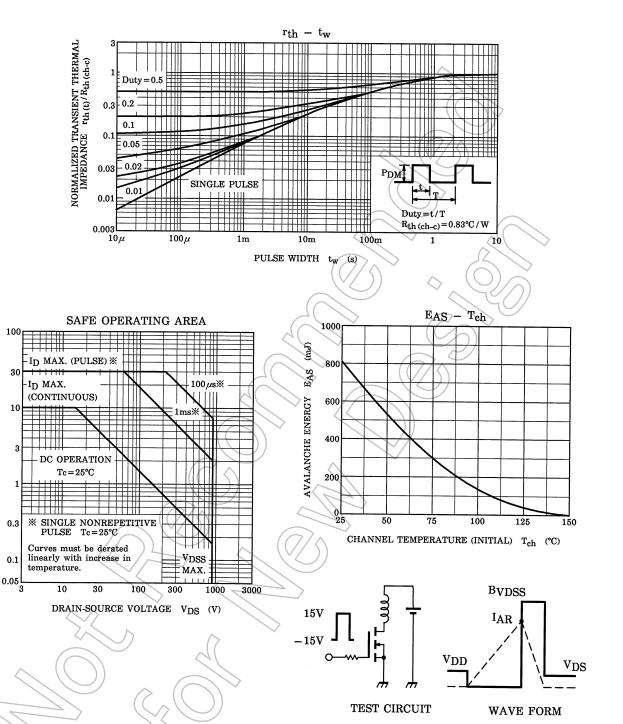
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I_D (A)

DRAIN CURRENT



 R_G = 25 Ω V_{DD} = 90 V, L = 14.9 mH

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 $E_{AS} = \frac{1}{2} \cdot L \cdot I^{2} \cdot \left(\frac{BVDSS}{BVDSS - VDD} \right)$

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